

Green Products

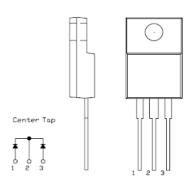
MBRF1060CTL SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

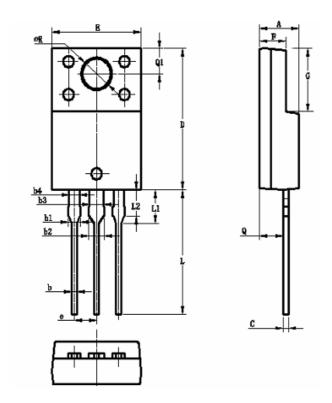
Features:

- 125 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



OUTLINE DRAWING

Mechanical Dimensions: In mm



	OPTION 1(CJ)		OPTIO	OPTION 2(HD)	
Dim	Min	Max	Min	Max	
Α	4.4	4.6	4.30	4.70	
b	0.6T	ΥP	0.50	0.75	
b1	1.3T	ΥP	1.30	1.40	
b2	1.7T	ΥP	1.70	1.80	
b3	1.6T	ΥP	1.50	1.75	
b4	1.2TYP		1.10	1.35	
С	0.60TYP		0.50	0.75	
D	14.8	15.1	14.80	15.20	
Е	10.06	10.26	9.96	10.36	
е	2.55TYP		2.54TYP		
F	2.9	3.1	2.80	3.20	
G	6.5	6.9	6.50	6.90	
L	12.7	13.7	12.8	13.2	
L1	3.4	3.8	3.60	4.00	
L2	2.6	3.0	-	-	
Q	2.5	2.9	2.50	2.90	
Q1	2.5	2.9	2.70REF		
ØR	3.5REF		3.50REF		

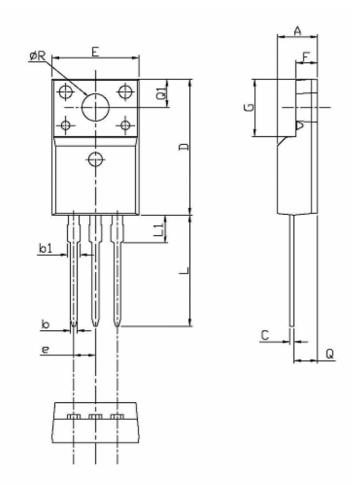
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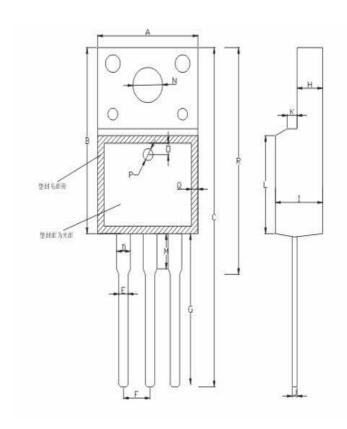


	OPTION 3		OPTION 4		
Dim	Min	Max	Min	Max	
Α	4.53	4.93	4.50	4.90	
b	0.71	0.91	0.70	0.90	
b1	1.15	1.39	1.33	1.47	
С	0.36	0.53	0.45	0.60	
D	15.67	16.07	15.67	16.07	
Е	9.96	10.36	9.96	10.36	
е	2.54TYP		2.54 BSC		
F	2.34	2.76	2.34	2.74	
G	6.50	6.90	6.48	6.88	
L	12.37	12.77	12.78	13.18	
L1	2.23	2.63	3.03	3.43	
			2 FC	2.96	
Q	2.56	2.96	2.56	2.90	
Q Q1	3.10	3.50	3.10	3.50	

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A:10.20	± 0.50	B:15.90	±0.50	C:29.00	±1.00	D:1.24	± 0.10
E:0.80	± 0.10	F:2.54	± 0.10	G:13.10	$\pm 1,0$	H:2.55	± 0.05
I:4.70	±0.05	J:0.50	± 0.05	K:1.20	±0.20	L:8.00	± 0.50
M:3.00				O:1,25	± 0.05	P:1.5	± 0.05
Q:1.0	±0.20	R:19.2	±1.0				

OPTION 5(SR)

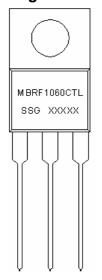
ITO-220AB





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Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type F = Package Type

10 = Forward Current (10A) 60 = Reverse Voltage (60V)

CTL = Configuration

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package Package	Shipping
MBRF1060CTL	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	60	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C = 75℃, rectangular wave form	10	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	IFSM	8.3 ms, half Sine pulse	125	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 5A, Pulse, T _J = 25°C	0.60	V
(per leg) *	V_{F2}	@ 5 A, Pulse, T _J = 100°C	0.55	V
Max. Reverse Current (per	I _{R1}	@V _R = rated VR	1.0	mA
leg) *		T _J = 25°C		
	I_{R2}	@V _R = rated VR	15	mA
		T _J = 100℃		
Max. Junction Capacitance	C_T	@V _R = 5V, T _C = 25°C	220	pF
(per leg)		$f_{SIG} = 1MHz$		
Typical Series Inductance	L _S	Measured lead to lead 5 mm from	8.0	nH
(per leg)		package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

^{*} Pulse Width < 300µs, Duty Cycle <2%

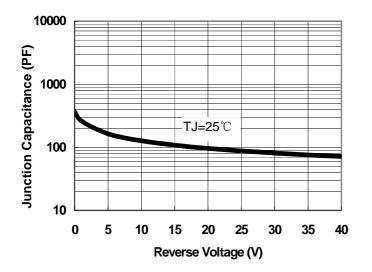
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature Range	TJ	-	-55 to +125	°C
Storage Temperature Range	T _{stg}	-	-55 to +125	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	3.5	°C/W
Maximum Thermal Resistance Case to Heat Sink	$R_{\theta JS}$	DC operation	60	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		

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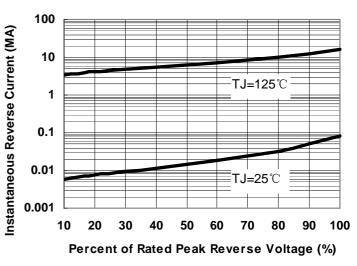


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

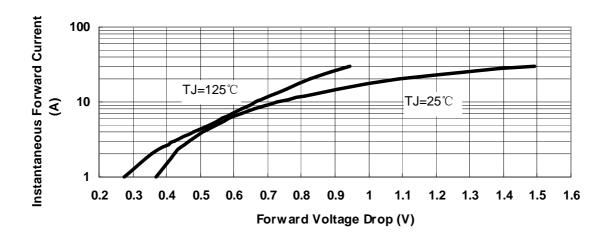


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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MBRF1060CTL

Technical Data
Data Sheet N0147 Rev. A

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